

Power Schottky rectifier

Feature

- High junction temperature capability
- Avalanche rated
- Low leakage current
- Good trade-off between leakage current and forward voltage drop

Description

Dual center tap Schottky rectifier suited for high frequency switch mode power supply.

Packaged in TO-220AB and I²PAK, this device is intended to be used in notebook and LCD adaptors, desktop SMPS, providing in these applications a margin between the remaining voltages applied on the diode and the voltage capability of the diode.

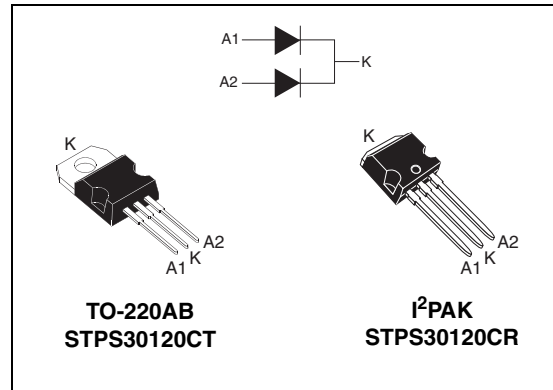


Figure 1. Electrical characteristics (a)

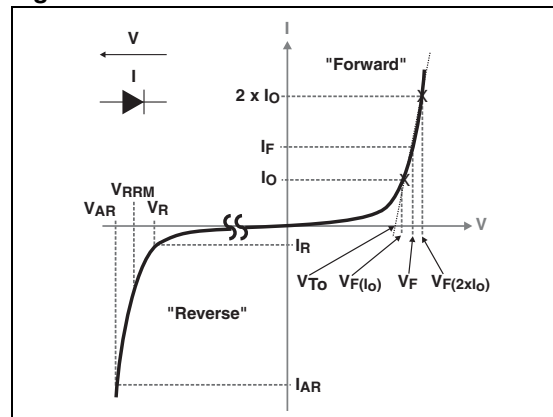


Table 1. Device summary

Symbol	Value
$I_{F(AV)}$	2 x 15 A
V_{RRM}	120 V
$T_{j(max)}$	175 °C
$V_{F(typ)}$	0.57 V

- a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in Figure 11. V_{AR} and I_{AR} are pulse measurements ($t_p < 1 \mu s$). V_R , I_R , V_{RRM} and V_F are static characteristics.

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		120	V
$I_{F(RMS)}$	Forward rms current		30	A
$I_{F(AV)}$	Average forward current	$\delta = 0.5$ $T_c = 145\text{ °C}$	Per diode 30	A
I_{FSM}	Surge non repetitive forward current		$t_p = 10\text{ ms}$ sinusoidal	180 A
P_{ARM}	Repetitive peak avalanche power		$t_p = 1\text{ }\mu\text{s}$ $T_j = 25\text{ °C}$	6700 W
$V_{ARM}^{(1)}$	Maximum repetitive peak avalanche voltage	$t_p = 1\text{ }\mu\text{s}$, $T_j < 150\text{ °C}$, $I_{AR} < 13.4\text{ A}$		150 V
$V_{ASM}^{(1)}$	Maximum single pulse peak avalanche voltage	$t_p = 1\text{ }\mu\text{s}$, $T_j < 150\text{ °C}$, $I_{AR} < 13.4\text{ A}$		150 V
T_{stg}	Storage temperature range		-65 to + 175	°C
T_j	Maximum operating junction temperature ⁽²⁾		175	°C

1. Refer to [Figure 11](#)

2. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal parameters

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	Per diode Total	2.2 1.3	°C/W
$R_{th(c)}$	Coupling		Total	0.3 °C/W

When the diodes 1 and 2 are used simultaneously :

$$T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

Table 4. Static electrical characteristics (per diode)

Symbol	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ }^\circ\text{C}$	$V_R = V_{RRM}$		15	μA
		$T_j = 125\text{ }^\circ\text{C}$			2.5	7.5
$V_F^{(2)}$	Forward voltage drop	$T_j = 25\text{ }^\circ\text{C}$	$I_F = 5\text{ A}$		0.74	V
		$T_j = 125\text{ }^\circ\text{C}$			0.57	
		$T_j = 25\text{ }^\circ\text{C}$	$I_F = 15\text{ A}$		0.92	
		$T_j = 125\text{ }^\circ\text{C}$			0.7	
		$T_j = 25\text{ }^\circ\text{C}$	$I_F = 30\text{ A}$		1.02	
		$T_j = 125\text{ }^\circ\text{C}$			0.83	

1. Pulse test : $t_p = 5\text{ ms}$, $\delta < 2\%$

2. Pulse test : $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = 0.59 \times I_{F(AV)} + 0.01 I_{F(RMS)}^2$$

Figure 2. Average forward power dissipation versus average forward current (per diode)

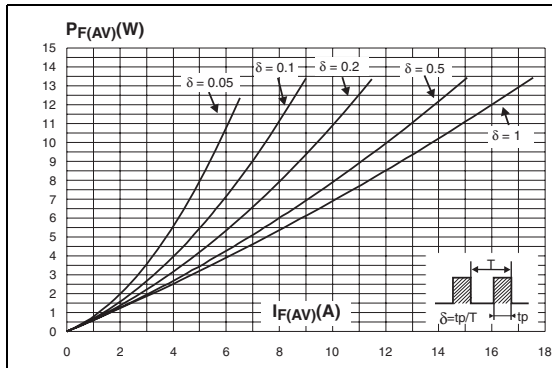


Figure 3. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

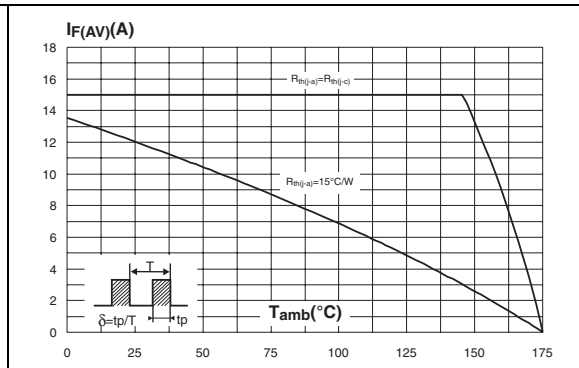


Figure 4. Normalized avalanche power derating versus pulse duration

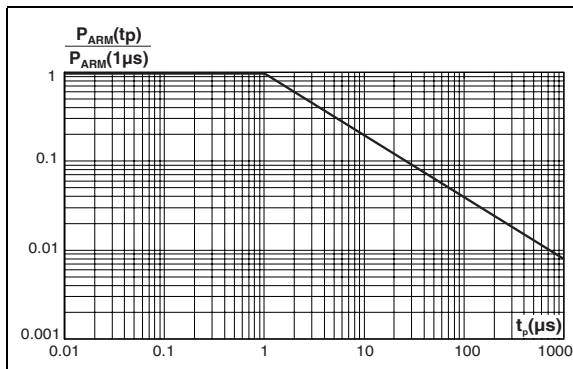


Figure 5. Normalized avalanche power derating versus junction temperature

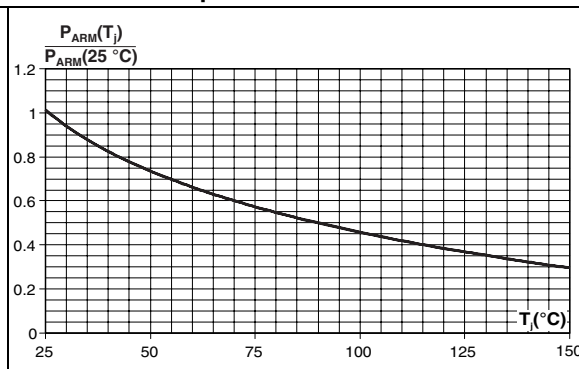


Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

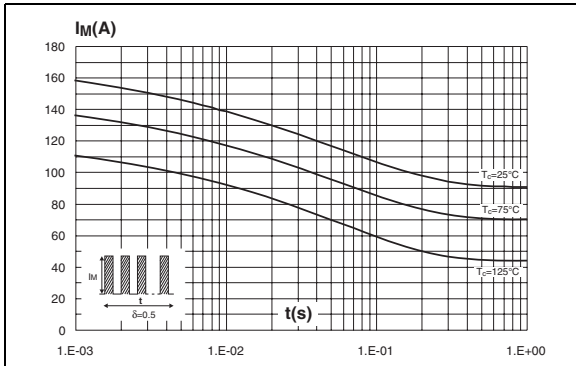


Figure 7. Relative variation of thermal impedance junction to ambient versus pulse duration

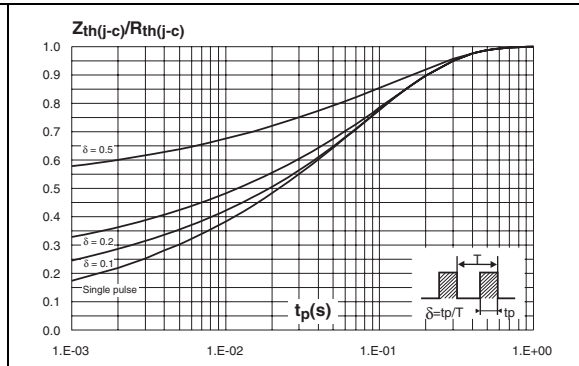


Figure 8. Reverse leakage current versus reverse voltage applied (typical values, per diode)

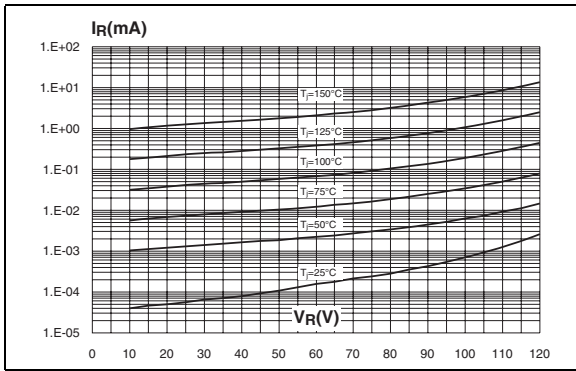


Figure 9. Junction capacitance versus reverse voltage applied (typical values, per diode)

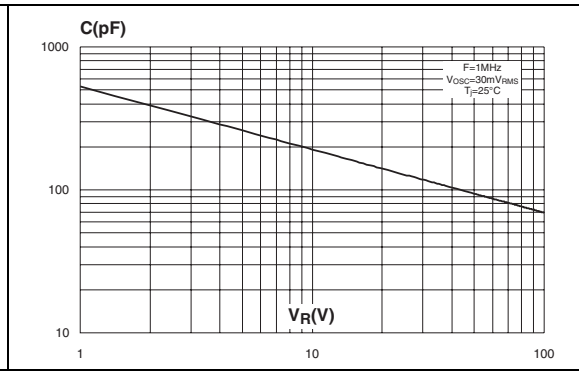


Figure 10. Forward voltage drop versus forward current (per diode)

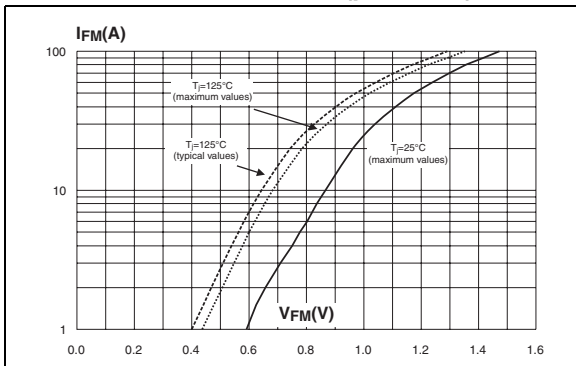
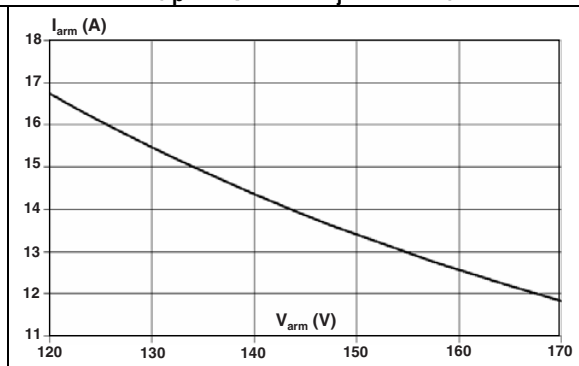


Figure 11. Reverse safe operating area ($t_p < 1 \mu\text{s}$ and $T_J < 150^\circ\text{C}$)



2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

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Table 5. TO-220AB dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

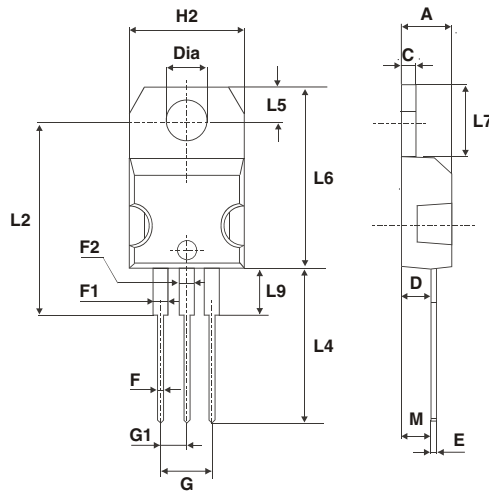


Table 6. I²PAK dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.40	2.72	0.094	0.107
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.044	0.067
c	0.49	0.70	0.019	0.028
c2	1.23	1.32	0.048	0.052
D	8.95	9.35	0.352	0.368
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
E	10	10.40	0.394	0.409
L	13	14	0.512	0.551
L1	3.50	3.93	0.138	0.155
L2	1.27	1.40	0.050	0.055

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS30120CT	STPS30120CT	TO-220AB	2.23 g	50	Tube
STPS30120CR	STPS30120CR	I ² PAK	1.49 g	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
18-Feb-2005	1	First issue.
23-Nov-2006	2	Reformatted to current standards. Added I ² PAK package.
17-Feb-2010	3	Updated Table 2 . Added Figure 1 and Figure 11 .

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